

2STA1694

High power PNP epitaxial planar bipolar transistor

Features

- High breakdown voltage V_{CEO} = -120 V
- Complementary to 2STC4467
- Fast-switching speed
- Typical f_t = 20 MHz
- Fully characterized at 125 °C

Applications

Audio power amplifier

Description

The device is a PNP transistor manufactured using new BiT-LA (Bipolar transistor for linear amplifier) technology. The resulting transistor shows good gain linearity behaviour.

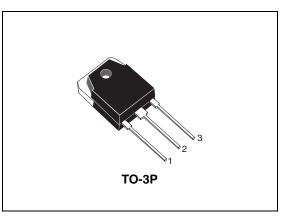


Figure 1. Internal schematic diagram

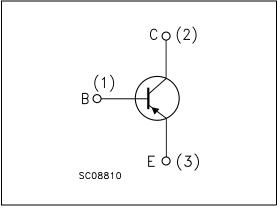


Table 1. Device summary

Order code	Marking	Package	Packaging
2STA1694	2STA1694	TO-3P	Tube

1 Electrical ratings

Table 2.	Absolute maximum ratings		
Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage $(I_E = 0)$	-120	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	-120	V
V _{EBO}	Emitter-base voltage (I _C = 0)	-6	V
Ι _C	Collector current	-8	А
I _{CM}	Collector peak current (t _P < 5 ms)	-16	А
P _{TOT}	Total dissipation at $T_c = 25 \ ^{\circ}C$	80	W
T _{stg}	Storage temperature	-65 to 150	°C
TJ	Max. operating junction temperature	150	°C

Table 2. Absolute maximum ratings

Table 3.Thermal data

Symbol	Parameter	Value	Unit
R _{thj-case}	Thermal resistance junction-case max	1.563	°C/W

2 Electrical characteristics

(T_{case} = 25 °C; unless otherwise specified)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current $(I_E = 0)$	V _{CB} = -120 V			-10	μA
I _{EBO}	Emitter cut-off current $V_{EB} = -6 V$				-10	μA
V _{(BR)CEO} ⁽¹⁾	Collector-emitter breakdown voltage (I _B = 0)	I _C = -50 mA	-120			V
V _{(BR)CBO}	Collector-base breakdown voltage (I _E = 0)	I _C = -100 μA	-120			V
V _{(BR)EBO} ⁽¹⁾	Emitter-base breakdown voltage (I _C = 0)	I _E = -1 mA	-6			V
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	I _C = -3 A I _B = -300 mA			-1.5	V
h _{FE}	DC current gain	$I_{\rm C} = -3 {\rm A} {\rm V}_{\rm CE} = -4 {\rm V}$	70		140	
f _T	Transition frequency	$I_{C} = -0.5 \text{ A} \text{ V}_{CE} = -12 \text{ V}$		20		MHz

Table 4. Electrical characteristics

1. Pulsed duration = 300 μ s, duty cycle $\leq 1.5\%$



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75 100 125 T_{case}(°C)

Electrical characteristics (curves) 2.1



Figure 3. **Derating curve**

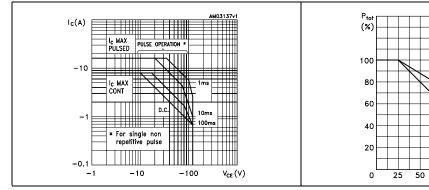


Figure 4. **Output characteristics**



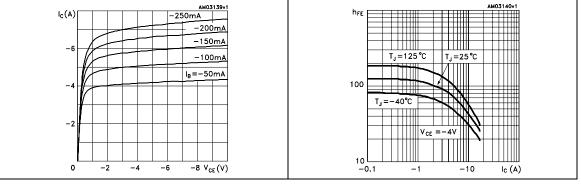
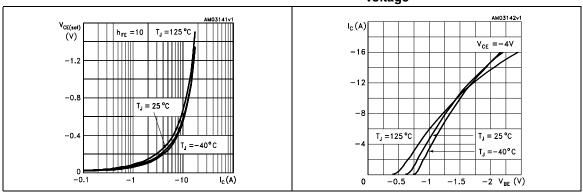


Figure 6. Collector-emitter saturation voltage Figure 7. Collector current vs base-emitter voltage

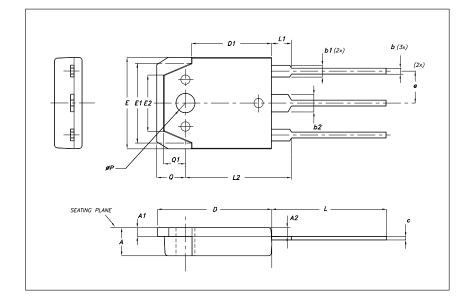


3 Package mechanical data

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TO-3P Mechanical data				
DIM.		mm.		
Diwi.	MIN.	ТҮР	MAX.	
A	4.6		5	
A1	1.45	1.50	1.65	
A2	1.20	1.40	1.60	
b	0.80	1	1.20	
b1	1.80		2.20	
b2	2.80		3.20	
с	0.55	0.60	0.75	
D	19.70	19.90	20.10	
D1		13.90		
E	15.40		15.80	
E1		13.60		
E2		9.60		
е	5.15	5.45	5.75	
L	19.50	20	20.50	
L1		3.50		
L2	18.20	18.40	18.60	
P	3.10		3.30	
Q		5		
Q1		3.80		



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4 Revision history

Table 5.Document revision history

Date	Revision	Changes
23-Nov-2007	1	Initial release
15-May-2008	2	Document status promoted from preliminary data to datasheet.
09-Feb-2009	3	Added section 2.1: Electrical characteristics (curves).



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